DETAIL SPECIFICATION

Semiconductor Device, Transistor,
PNP, Germanium, High Frequency, 25 Milliwatt, Type JAN-2N128

MIL-S-19500/9B, dated 26 March 2004, remains inactive for new design; however, the document is valid for use.

Custodians:                  Preparing Activity:
Army - CR                    DLA - CC
Navy - EC
Air Force - 85
DLA - CC

Reviewer Activities:
Army - AR, MI
Navy - AS, CG, MC
Air Force - 19, 99

NOTE: The activities above were interested in this document as of the date of this document. Since organizations and responsibilities can change, you should verify the currency of the information above using the ASSIST Online database at https://assist.daps.dla.mil.